SPICE Device Model SiB433EDK



Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

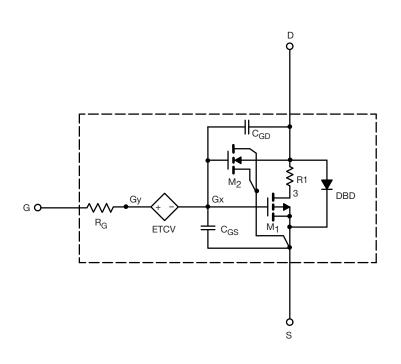
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge



Note

 This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	0.60	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3.7 \text{ A}$	0.051	0.047	Ω
		V _{GS} = - 2.5 V, I _D = - 3.2 A	0.068	0.064	
Forward Transconductance ^a	g fs	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -3.7 \text{ A}$	12	12	S
Diode Forward Voltage	V _{SD}	I _S = - 4.3 A	- 0.85	- 0.80	V
Dynamic ^b					
Total Gate Charge	Q _g Q _{gs}	V_{DS} = - 10 V, V_{GS} = - 8 V, I_{D} = - 5.3 A	10	14	nC
		V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_D = - 5.3 A	6	6	
Gate-Source Charge			0.8	0.8	
Gate-Drain Charge	Q _{gd}		3.1	3.1	

Note

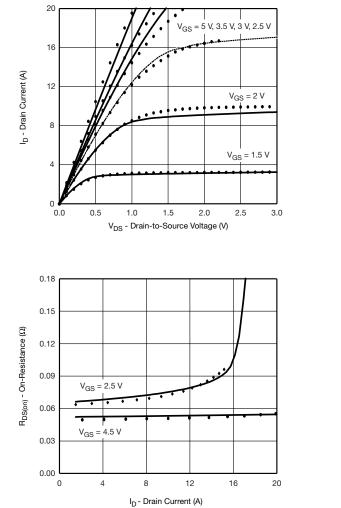
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

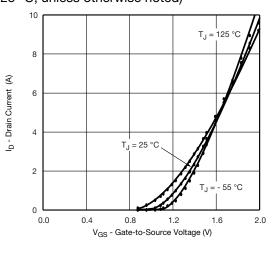
b. Guaranteed by design, not subject to production testing.

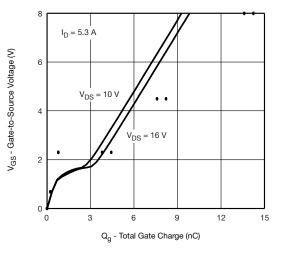


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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)







Note

• Dots and squares represent measured data.



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